

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT: SCHAUER ET AL 1 PCT

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TITLE: SEMICONDUCTOR WAFER COMPRISING A THIN EPITAXIAL
SILICON LAYER AND METHOD FOR PRODUCING THE SAME

PRELIMINARY AMENDMENT

ATT: BOX PCT APPLICATION
Assistant Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

Preliminary to examination please amend the above-identified
U.S. National Phase U.S. patent application as follows:

IN THE ABSTRACT:

Please insert the enclosed Abstract of the Disclosure attached
hereto on its own separate page.

IN THE SPECIFICATION:

Please amend the Specification as follows:

On page 1, above the first paragraph and below the title,
please insert the following paragraphs:

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